

Photomicrosensor (Transmissive)

EE-SJ3 Series

Slot/Terminal Type (Slot Width: 3.4 mm)

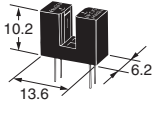
- Three aperture types
- Terminal for PCB mounting

 Be sure to read *Safety Precautions* on Page 3.



Ordering Information

Photomicrosensor

Appearance	Sensing method	Connecting method	Sensing distance	Aperture size (H × W) (mm) (Both emitting side and detecting side)	Output type	Model	Minimum packing unit (Unit: pcs)
	Transmissive (slot type)	Terminal for PCB mounting	3.4 mm (Slot width)	2.1 × 1	Phototransistor	EE-SJ3-C	1
				2.1 × 0.2		EE-SJ3-D	
				0.5 × 2.1		EE-SJ3-G	

Note: Order in multiples of minimum packing unit.

Ratings, Characteristics and Exterior Specifications

Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	Rated value	Unit
Emitter			
Forward current	I _F	50*1	mA
Pulse forward current	I _{FP}	1*2	A
Reverse voltage	V _R	4	V
Detector			
Collector-Emitter voltage	V _{CEO}	30	V
Emitter-Collector voltage	V _{ECO}	—	V
Collector current	I _C	20	mA
Collector dissipation	P _C	100*1	mW
Operating temperature	T _{opr}	-25 to 85	°C
Storage temperature	T _{stg}	-30 to 100	°C
Soldering temperature	T _{sol}	260*3	°C

*1. Refer to the temperature rating chart if the ambient temperature exceeds 25°C.

*2. Pulse width ≤ 10 μs, Repeated 100 Hz

*3. Complete soldering within 10 seconds.

Exterior Specifications

Connecting method	Weight (g)	Material	
		Case	Bottom plate
Terminal for PCB mounting	0.7	Polycarbonate	Polycarbonate

Electrical and Optical Characteristics (Ta = 25°C)

Item		Symbol	Value			Unit	Condition
			EE-SJ3-C	EE-SJ3-D	EE-SJ3-G		
Emitter							
Forward voltage	V _F	1.2 (TYP.) 1.5 (MAX.)			V	I _F = 30 mA	
Reverse current	I _R	0.01 (TYP.) 10 (MAX.)			μA	V _R = 4 V	
Peak emission wavelength	λ _P	940 (TYP.)			nm	I _F = 20 mA	
Detector							
Light current	I _L	1 to 28	0.1 (MIN.)	0.5 to 14	mA	I _F = 20 mA V _{CE} = 10 V	
Dark current	I _D	2 (TYP.) 200 (MAX.)			nA	V _{CE} = 10 V 0 lx	
Leakage current	I _{LEAK}	—			μA	—	
Collector-Emitter saturated voltage	V _{CE (sat)}	0.1 (TYP.) 0.4 (MAX.)	—	0.1 (TYP.) 0.4 (MAX.)	V	I _F = 20 mA I _L = 0.1 mA	
Peak spectral sensitivity wavelength	λ _P	850 (TYP.)			nm	V _{CE} = 10 V	
Rising time	t _r	4 (TYP.)			μs	V _{CC} = 5 V R _L = 100 Ω	
Falling time	t _f	4 (TYP.)			μs	I _L = 5 mA	

Engineering Data (Reference Value)

Fig 1. Forward Current vs. Collector Dissipation Temperature Rating

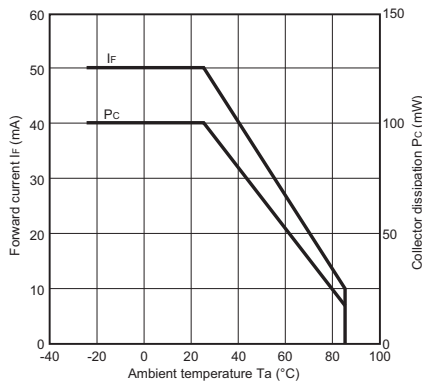


Fig 2. Forward Current vs. Forward Voltage Characteristics (Typical)

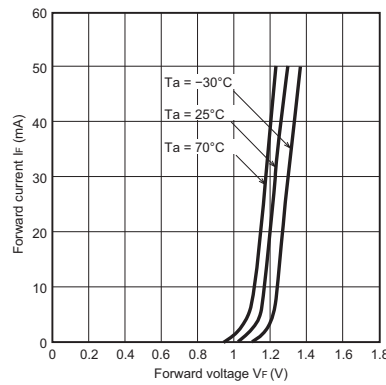


Fig 3. Light Current vs. Forward Current Characteristics (Typical)

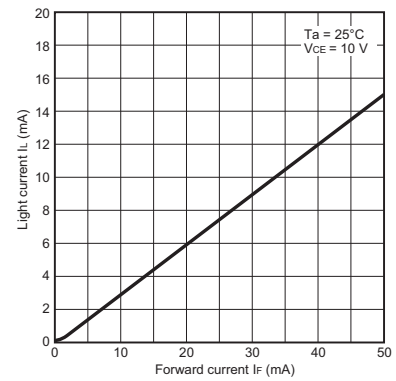


Fig 4. Light Current vs. Collector-Emitter Voltage Characteristics (Typical) EE-SJ3-G

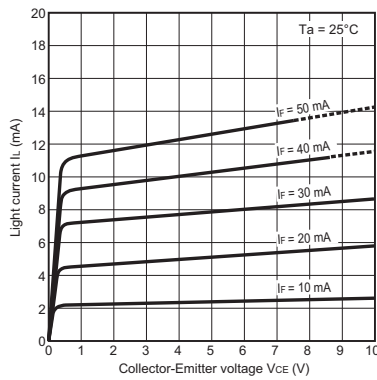


Fig 5. Relative Light Current vs. Ambient Temperature Characteristics (Typical)

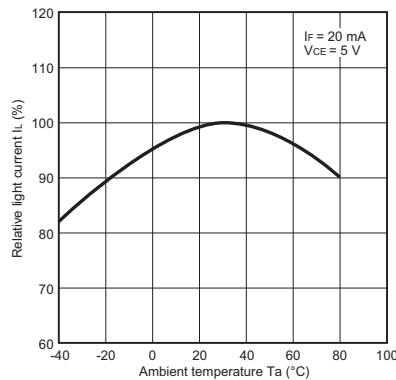


Fig 6. Dark Current vs. Ambient Temperature Characteristics (Typical)

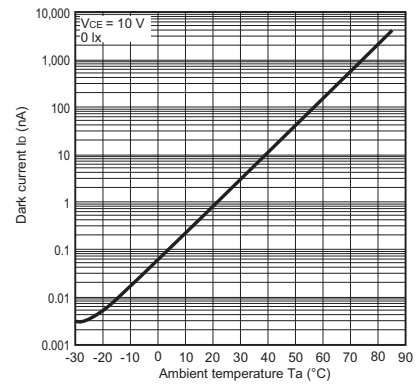


Fig 7. Response Time vs. Load Resistance Characteristics (Typical)

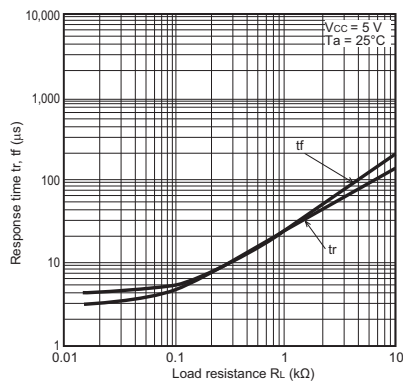


Fig 8. Sensing Position Characteristics (Typical) EE-SJ3-D

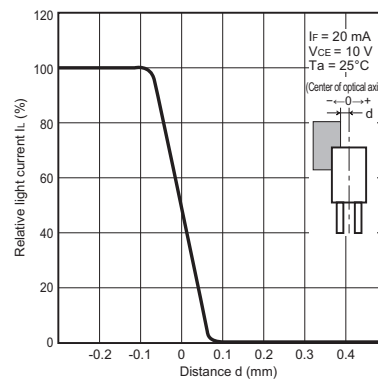


Fig 9. Sensing Position Characteristics (Typical) EE-SJ3-G

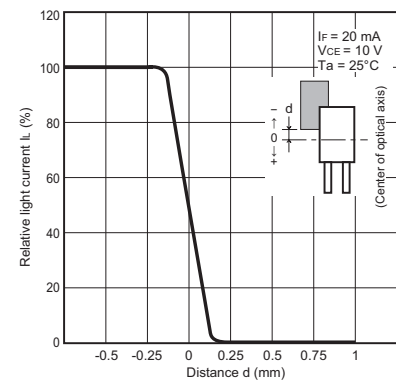


Fig 10. Sensing Position Characteristics (Typical) EE-SJ3-C

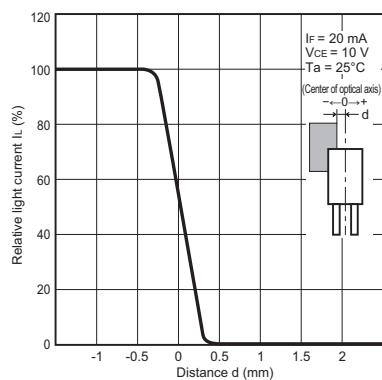
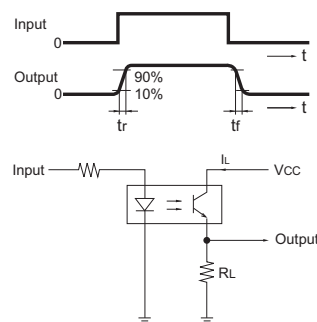


Fig 11. Response Time Measurement Circuit



Safety Precautions

To ensure safe operation, be sure to read and follow the Instruction Manual provided with the Sensor.

CAUTION

This product is not designed or rated for ensuring safety of persons either directly or indirectly.
Do not use it for such purposes.



Precautions for Correct Use

Do not use the product in atmospheres or environments that exceed product ratings.

Precautions for Safe Use

Do not use the product with a voltage or current that exceeds the rated range.

Applying a voltage or current that is higher than the rated range may result in explosion or fire.

Do not miswire such as the polarity of the power supply voltage.

Otherwise the product may be damaged or it may burn.

This product does not resist water. Do not use the product in places where water or oil may be sprayed onto the product.

Dimensions and Internal Circuit

(Unit: mm)

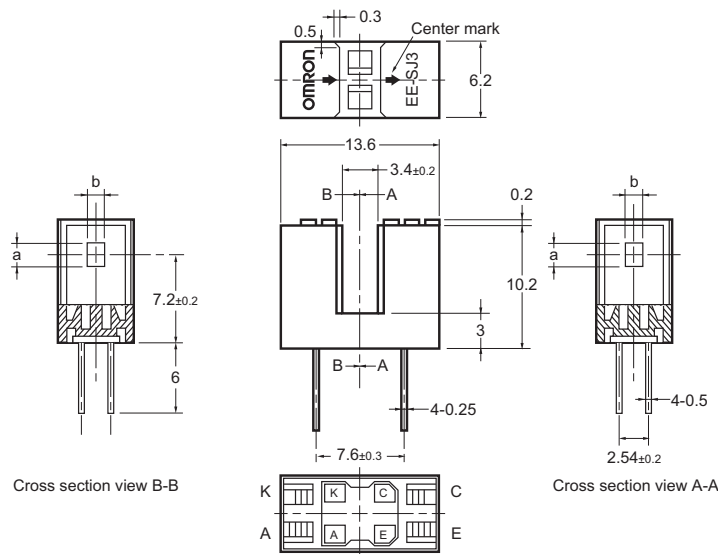
Photomicrosensor

EE-SJ3 Series

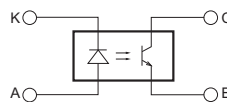


Aperture size (H × W)

Model	Aperture hole (a×b)
EE-SJ3-C	2.1 × 1
EE-SJ3-D	2.1 × 0.2
EE-SJ3-G	0.5 × 2.1



Internal circuit



Terminal No.	Name
A	Anode
K	Cathode
C	Collector
E	Emitter

Unless otherwise specified, the tolerances are as shown below.

Dimensions	Tolerance
3 mm max.	±0.3
3 < mm ≤ 6	±0.375
6 < mm ≤ 10	±0.45
10 < mm ≤ 18	±0.55
18 < mm ≤ 30	±0.65

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